# Analysis of the Adhesion of Particles to Thin Films:

## **CMP/Post-CMP Cleaning Applications**

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# Outline

## Motivation

## •First Generation Model

- Model Description
- Experimental Procedure
- Experimental Validation

## Second Generation Model

- Description
- Predictions

## Model Implications





## **Adhesion Importance in Semiconductor Industry**

#### •Necessary boundary condition in modeling of post-

**CMP cleaning** 



Alumina or silica slurry left on silicon, SiO<sub>2</sub>, or metal film after CMP

#### •Important characteristic in developing both barrier

layers and thin films (both ILD and metal)







# **Post-CMP Cleaning Research**







# **Adhesion Investigation Strategy**



# **1**<sup>st</sup> Generation Model







# Van der Waals (vdW) Models





**Ideal vdW**- No deformation single contact point



**Our Roughness model** - colloid deformation with rigid discrete hemispherical asperity contacts



**Extended vdW**- colloid deformation continuous contact area



## **AFM Force Measurement**







# **Colloid - Surface Contact Area Measurement**



#### **PSL** spheres on Silicon





## **Comparison of Experimental Observation with Theory**



**Removal Force (nN)**